Testingofn-ABCD2metalizedchipsonthe Barrel Kapton hybrid/module

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Abstract

The n-strip readout ABCD2 chips which were thinned and metalized in the backside were stuffed on the kapton hybrids developed for the SCT Barrel module. A 6 chips hybrid was connected to 6cm strips and then 12 cm strips daisy-chaining two square barrel detectors. All channels with 6 cm strips were stable for the maximum range of FE bias current, 285 μ A, with the nominal FE shaper current at 18 μ A. Channels with 12 cm strips developed instability for the number of strips more than 40. The instability were suppressed for the full range of FE bias current up to 285 μ A by setting the FE shaper current at 10 μ A in the setup. A fully stuffed module, 12 chips and 4 detectors, was fabricated and performance was mapped out for the combination of FE bias and shaper currents. Instability was observed in the region of FE shaper current being >8 μ A and FE bias current >147 μ A. With the FE shaper current being below 8 μ A the chips worked for the full range of FE bias currents up to 285 μ A. However, the chips were still unstable for the thresholds below about 50 mV.



Next plans

(as of Feb. SCT week, $\sqrt{}$ as of June SCT week)

- $\sqrt{\text{Stuff}}$ the hybrid with more chips, e.g., 6 chips
- \sqrt{Bond} (most of) channels to (single) detector
 - 6 cm in this configuration

- 12 cm requires "ganging" and not practical for this

- 12 cm "ganging" is possible by using the "irradiation pitch adaptor", but only 4 chips per hybrid

- 12 cm: 2 detectors in series

√If the single detector operation is successful,...

- A few more chips (which we have so far) on the other side, and

• \sqrt{Build} a double-side Barrel module

- If the operation is successful, which is a BIG question mark, then...

 Start building the "back-metalized" p-ABCD module as soon as possible

- There might be a surprise in the p-chips...



End-tap half module - 6 chips with 2 detectors

-BarrelKaptonhybridbeingpopulatedwith6n-ABCD2-metalized chips

- Analog and Digital grounds were connected on the hybrid

-Carbon-carbonbridgebeinggluedonthehybridwithelectrically conductive glue where the chips were, i.e., "conductive bridge"

-ThehybridandthedetectorswereplacedonanAluminiumsupport plate

-ThehybridbridgewaselectricallyconnectedtotheAluminiumplate

-Severalattemptsweretriedtoimprovetheinstabilitysituation,e.g., additionofthere-inforcingelectricalwireconnectionsasseeninthe photo, which did not help to improve the situation, though

6 cm strips

-AllchipswerestablefortheFEbiascurrentsupto285 μ A,withthe FE shaper current at 18 μ A

- 50% median charge, noise charge, in the unit of mV

At 212 μA,..., 285 μA,
90 mV threshold ~ <1 fC
Noise charge:
~ 0.17 fC (~1100 e) at 212 μA
~ 0.15 fC (~ 950 e) at 285 μA

- Dead strips ~ 10

matched with the dead strips of the n-on-n detectors No systematic study, though



Two chips-alternative 12 cm strips

(1) Alternative channels to form 12 cm strips

- First 2 chips, "alternative" 64 channels were 12 cm

-12cm-stripchannelsofthefirst2chipswereunstable,withastrange channelspattern, i.e., the chip-edge channels were as stable as expectedbuttheinstabilityincreased toward the centre-channelsof the chip

- Other 6cm-strip chips were stable

(2)Disablingthefirst2chips,andincreasingthe12cmstrip channels step-by-step

-Thelastchip,E5,stepof5,10,15,20stripsfromtwoedges,(x10,x20, x30, x40)

- Atx40, although the noise charge figures were still reasonable, "noisescan"showed" instability" in the occupancy plotas a function of the thresholds, "double-peak"

-The above is at the FE shaper current at 18 μ A. Reduction of the shaper current to 10 μ A, suppressed the instability, and the chipswere stable over the full range of FE bias current, up to 285 μ A

- The first 2 chips, which showed instability before, were quiet







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Full module - 12 chips and 4 detectors

-Encouragedwiththeresultofthe"End-taphalfmodule",aBarrel "centre-tapped" full module was fabricated and tested

- A fully populated 12 chips Kapton hybrid

- Analog and Digital grounds were connected on the hybrid

-Carbon-carbonbridge,conductivelyconnectedtothechipground, i.e., "conductive bridge"

-Polyimide-coatedTPGbaseboard,beingusedtoconductthehigh voltage from the hybrid to the backplane of the detectors

-Hybrid-bridge and the baseboard was insulted with AIN facings



Qsigma vs Ch



Results
(1) Scanning the operationable range
-FEbiasandshapercurrentswerescannedinordertoinvestigatethe operationable region in the parameter space
-Thenoisechargeshowedthefullchipswerestablewherethegainis low,i.e.,either"lowFEbiasandhighshapercurrents"or"highFEbias and low shaper currents"
- Examples of the charge injection scan
- Low bias and high shaper currents:
Lower noise, 0.23~0.25 fC (1450 ~ 1560 e)
Larger spread in channel uniformity
- High bias and low shaper currents:
Larger noise, ~ 0.28 fC (~ 1750 e)
Smaller spread in uniformity
- Gain was smaller, 70 ~ 80 mV/fC
- Still "unstable" in the thresholds <50 mV







Summary

(1)Halfandfullmoduleswerefabricatedwithn-ABCD2-metalized chips

(2)OntheBarrelKaptonhybrid,thechipswerestableinthefullrange of FE biascurrent with the shaper current at the nominal value of 18 μ A for the 6 cm strips

(3) Morethan 40 strips being connected to 12 cm-strips, the chips started to show "instability"

(4) Lowering the gain by reducing the FE shaper current improved the instability

(5)Thefullmodulewasoperationableinthelowgainregime,either withhighFEbiasandlowshapercurrentorwithlowFEbiasandhigh shaper currents

(6)ThenoiseperformancewasbetterinthelowFEbiascurrent,but the channel uniformity was better in the high FE bias current